

KSC5019

Low Saturation

• $V_{CE}(sat)=0.5V$ at $I_{C}=2A$, $I_{B}=50mA$ WWW.BZSC.COM



1. Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	30	V
V _{CES}	Collector-Emitter Voltage	30	V
V _{CEO}	Collector-Emitter Voltage	10	V
V _{EBO}	Emitter-Base Voltage	6	V
c	Collector Current (DC)	2	Α
СР	* Collector Current (Pulse)	5	Α
В	Base Current	2	Α
P _C	Collector Power Dissipation	750	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

^{*} PW≤10ms, Duty Cycle≤30%

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I _{CBO}	Collector Cut-off Current	V_{CB} =30V, I_E =0			100	nA
I _{EBO}	Emitter Cut-off Current	V _{EB} =6V, I _C =0			100	nA
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =10mA, I _B =0	10			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =1mA, I _C =0	6			V
h _{FE1}	DC Current Gain	V _{CE} =1V, I _C =0.5A	140	RES.	600	0.00
h _{FE2}		V _{CE} =1V, I _C =2A	70	200	M.Dr.	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =2A, I _B =50mA		0.2	0.5	V
V _{BE} (on)	Base Emitter On Voltage	V _{CE} =1V, I _C =2A		0.86	1.5	V
f _T	Current Gain Bandwidth Product	V _{CE} =1 <mark>V, I_C=0.5</mark> A		150		MHz
C _{ob}	Output Capacitance	V_{CB} =10V, I_E =0, f=1MHz		27		pF

h _{FE} Classification	WW.DZSD.W			
Classification	L	M	N	Р
h _{FE}	140 ~ 240	200 ~ 330	300 ~ 450	420 ~ 600

Typical Characteristics

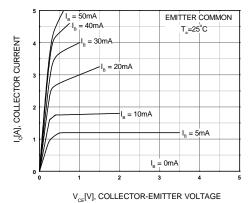


Figure 1. Static Characteristic

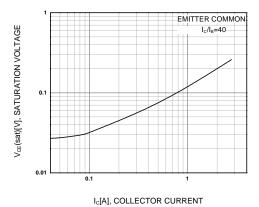


Figure 3. Collector-Emitter Saturation Voltage

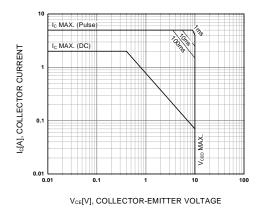


Figure 5. Safe Operating Area

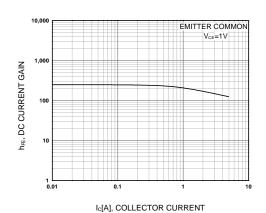


Figure 2. DC current Gain

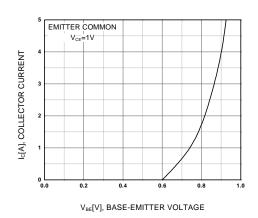


Figure 4. Base-Emitter On Voltage

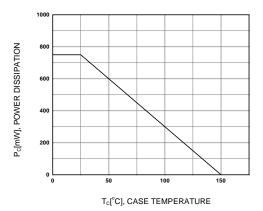
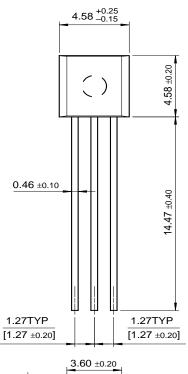


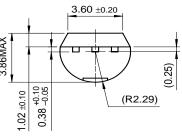
Figure 6. Power Derating

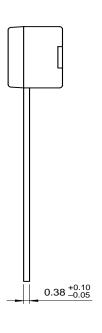
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Package Dimensions

TO-92







Dimensions in Millimeters

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CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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